## NSN 5962-01-430-2125

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## View Online at https://aerobasegroup.com/nsn/5962-01-430-2125 **Body Length:** 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 1.5 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Pacer dawn **Features Provided:** Bipolar and burn in and erasable and monolithic and programmed and electrostatic sensitive **Inclosure Material:** Ceramic Inclosure Configuration: Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 18 input **Criticality Code Justification:** Cbbl **Case Outline Source And Designator:** D-8 mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** Microcircuit, programmable array logic, 1553 decode Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source Memory Device Type: Pal **Special Features:** Altered item, programmable to drwg. Cp34099891 file number 99891-01 make from 5962-8983901ra **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A458a0

